

## **Quarterly Reliability Monitoring Results**

Quarters: Q1/2021 to Q4/2021

Based on structural similarity

| Supplier   |   | User Part Number                                     |                       |           |            |           |  |  |
|--|---|--|-----------------------|-----------|------------|-----------|--|--|
| Nexperia B.V.<br>Name of Laboratory<br>Assembly reliability labs<br>Based on AEC-Q101 Test |   | PEMB11   |                       |           |            |           |  |  |
|  |   | Part Description                                     |                       |           |            |           |  |  |
|  |   | Nexperia DHAM Small Signal Bipolar Transistor        |                       |           |            |           |  |  |
|  |   | SMD package  |                       |           |            |           |  |  |
|  |   | Test Conditions                                      | Duration              | # Lots    | # Quantity | # Rejects |  |  |
|  | TEST                                      |  |                       |           |            |           |  |  |
|  | Pre- and Post-Stress                      |  |                       |           |            |           |  |  |
| # E1   | Electrical Test                           | Tamb = 25 °C   | N/A                   | see below | all parts  | see below |  |  |
|  |   | JESD22-A113  |                       |           |            |           |  |  |
|  | PC  | Bake Tamb = 125 °C                                   | 24 hours<br>168 hours |           |            |           |  |  |
| # A1   | Preconditioning                           | Soak Tamb = 85 °C, RH = 85%<br>Reflow soldering      | 3 cycles              | 849       | 61170      | 0         |  |  |
| # A1   | Treconditioning                           |  | 5 cycles              | 849       | 61170      | U         |  |  |
|  | HTRB                                      | MIL-STD-750-1<br>M1039 Method A                      |                       |           |            |           |  |  |
|  |   | Tj = Tjmax, Vr = $100\%$ of max. datasheet           |                       |           |            |           |  |  |
| # B1   | Bias                                      | reverse voltage                                      | 1000 hours            | 202       | 16160      | 0         |  |  |
| # 01   |   |  |                       |           |            | -         |  |  |
|  | тс  | JESD22-A104  |                       |           |            |           |  |  |
| # A4   | Temperature Cycling                       | -65 °C to Tjmax, not to exceed 150°C                 | 1000 cycles           | 171       | 13680      | 0         |  |  |
|  |   | JESD22-A102  |                       |           |            |           |  |  |
|  | AC  | Tamb = 121 °C, RH = 100 %                            |                       |           |            |           |  |  |
| # A3 alt   | Autoclave                                 | Pressure = 205 kPa (29.7 psia)                       | 96 hours              | 173       | 13840      | 0         |  |  |
|  |   |  |                       |           |            |           |  |  |
|  | H3TRB                                     | JESD22-A101  |                       |           |            |           |  |  |
|  | High Humidity High                        | Tamb = 85 °C, RH = 85%, VR = 80 % of                 |                       |           |            |           |  |  |
| # A2 alt   | Temperature Reverse Bias                  |  | 1000 hours            | 173       | 13840      | 0         |  |  |
|  | 101                                       | MIL-STD-750 Method 1037                              |                       |           |            |           |  |  |
| # A F  | <b>IOL</b><br>Intermittent Operating Life | ton = toff, devices powered to insure $\Delta T j$ = | 1000 have             | 107       | 15360      | 0         |  |  |
| # A5   | Internittent Operating Life               |  | 1000 hours            | 197       | 15760      | 0         |  |  |
|  | RSH                                       | JESD22-A111  |                       |           |            |           |  |  |
| # C8   | Resistance to Solder Heat                 |  | 10 s                  | 135       | 4050       | 0         |  |  |
| # C0   | SD  |  | 10.2                  | 100       | -000       | v         |  |  |
| # C10  | Solderability                             | J-STD-002  |                       | 342       | 3420       | 0         |  |  |
|  |   | d by test chamber set up and does not exceed         |                       | J72       | 5420       | v         |  |  |

[1] The maximum applied voltage is limited by test chamber set up and does not exceed 115V.

## **Calculation of FIT and MTTF**

Test considered for FIT calculation: High Temperature Reverse Bias (HTRB, Test #B1) Confidence level 60%, derated to 55 °C, activation energy 0.7 eV, test time 168 to 1000 hours

| Wafer Fab        | Technology                         | Quantity | Rejects | Failure Rate (FIT) | MTTF (hrs) |
|------------------|------------------------------------|----------|---------|--------------------|------------|
| Nexperia<br>DHAM | Small Signal Bipolar<br>Transistor | 16160    | 0       | 0.26               | 3.81E+09   |

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